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# Optimizing transmittance in WO<sub>3</sub>-based electrochromic films: advanced growth control via chemical bath deposition

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Tungsten trioxide (WO<sub>3</sub>)-based electrochromic film is a promising component for all-solid-state electrochromic devices, which can be used in smart windows to control the indoor temperature and incident solar irradiation. However, its practical application suffers from significant challenges including slow switching kinetics, low cycling stability, and high production costs. To overcome these limitations, a mild chemical bath deposition approach is introduced. Through strategic control of reactants, the thickness of the WO<sub>3</sub> film and the constituent WO<sub>3</sub> nanosheets forming the film can both be systematically regulated. The optimized W<sub>2</sub> sample demonstrates remarkable electrochromic performance, achieving an optical modulation amplitude of  $\Delta T = 67.85\%$  at 620 nm along with good cycling stability, which was caused by its well-engineered hierarchical structure featuring a thin film configuration (430 nm) composed of ultrathin nanosheets (39.48 nm). This work points out a new strategy for modulating the optical properties of WO<sub>3</sub> electrochromic film through reactant control during a chemical bath deposition process, providing valuable insights for the rational design of high-performance smart windows.

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## 1 Introduction

In the 21st century, energy and the environment are the most concerning issues for all people worldwide. Among all energy consumption fields, buildings consume about 20–40% of the world's energy generation, which is mainly through heating, ventilation, air conditioning (HVAC) systems and lighting systems.<sup>1–3</sup> As a promising solution, smart windows can inhibit the transmission of visible and infrared light in summer, thereby reducing the energy consumption of HVAC systems. The electrochromic device (ECD) is an important part of smart windows, which is combined with a conducting transparent conductive electrode (TCE), electrochromic layer, electrolyte, and ion-storage layer.<sup>2,4–13</sup> While all components have been systematically investigated, the electrochromic layer remains the most visually distinctive element due to its reversible optical transitions. This unique characteristic stems from electrochemical redox reactions that induce controllable variations in light absorption spectra under applied electrical potentials.

WO<sub>3</sub> is one of the most extensively studied electrochromic materials and currently the sole commercially implemented option for smart window applications.<sup>14–18</sup> This transition metal oxide exhibits reversible optical switching behavior, transitioning to a blue-colored state under cathodic

polarization while recovering optical transparency upon anodic polarization. Notably, this electrochromic performance is critically dependent on the nanoscale thickness and crystalline microstructure of the electrochromic layer.<sup>5,7,8,12,13,19–21</sup>

Previous studies have revealed that exceeding 1  $\mu\text{m}$  in thickness induces irreversible structural modifications, manifested by yellow or white coloration and a deterioration in visible light transmittance.<sup>13,20,22–29</sup>

In previous works, many methods have been used to fabricate WO<sub>3</sub> electrochromic films under 1  $\mu\text{m}$ . Compared with traditional sol-gel, sputtering, and hydrothermal methods, the chemical bath deposition method has been favored for its low cost and process temperature and structural control. Though the chemical bath method has been used in some previous reports, the obtained samples showed unsatisfactory performance, especially for the optical modulation amplitude.<sup>30–35</sup>

Building upon our prior study, a WO<sub>3</sub> film was fabricated on SnO<sub>2</sub>:F (FTO) glass by a chemical bath method. In this work, the growth processes were further investigated and an *in situ* electrochromic test was carried out to evaluate the electrochromic properties.

## 2 Experimental

### 2.1 Chemicals

Sodium tungsten oxide dihydrate (Na<sub>2</sub>WO<sub>4</sub>·2H<sub>2</sub>O) and oxalic acid (H<sub>2</sub>C<sub>2</sub>O<sub>4</sub>) were purchased from Aladdin Chemicals Co.

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Hydrochloric acid (HCl) was purchased from Sinopharm Chemical Reagent Co. Ltd. All chemicals were used without any further purification. FTO glass with a sheet resistance of  $14\text{--}16\ \Omega\ \text{sq}^{-1}$  was obtained from Zhuhai Kaivo Optoelectronic Technology Co., and was cut into a size of  $1\ \text{cm} \times 5\ \text{cm}$ . This was cleaned by sonication with acetone, ethanol and DI water in sequence before use.

## 2.2 Synthesis of $\text{H}_2\text{WO}_4$ film on FTO

Solution A was prepared by dissolving 6.6 g  $\text{Na}_2\text{WO}_4 \cdot 2\text{H}_2\text{O}$  in 100 mL deionized water (DI water). Solution B was formulated by dissolving 3.6 g of  $\text{H}_2\text{C}_2\text{O}_4$  in 100 mL DI water. For the chemical bath deposition, 0.5 mL of both solution A and B were transferred to a 12 mL polypropylene centrifuge tube. The mixture was diluted to 3 mL with DI water, followed by addition of 2 mL HCl (2 M) to achieve a final pH < 1. The FTO glass was positioned in the reaction tube with the conductive surface facing downward against the tube wall. The sealed reaction system was kept in a preheated metal heating block maintained at  $60\ ^\circ\text{C}$  for 3 h. After the reaction time, the synthesized  $\text{H}_2\text{WO}_4/\text{FTO}$  samples were taken out immediately and rinsed with DI water and ethanol several times to remove the residual reactants. Then it was dried at  $60\ ^\circ\text{C}$  for 12 h and marked as  $\text{H}_5$ . Thermal conversion to  $\text{WO}_3/\text{FTO}$  was achieved through calcination in a muffle furnace at  $500\ ^\circ\text{C}$  for 3 h, inducing a chromatic transition from light yellow to pale white; the annealed specimen was labeled as  $\text{W}_5$  (Fig. 1). A series of samples was fabricated by similar steps except for systematically varying the volume of solution B; these were named  $\text{H}_1$  to  $\text{H}_9$  before annealing and  $\text{W}_1$  to  $\text{W}_9$  after annealing. Full parametric details are shown in Table S1 in the SI.

## 2.3 Characterization

The structure of the as-prepared  $\text{H}_2\text{WO}_4/\text{FTO}$  and  $\text{WO}_3/\text{FTO}$  samples were characterized by XRD (SmartLab SE, Rigaku, Japan) using a Cu K $\alpha$  radiation ( $\lambda = 0.15418\ \text{nm}$ ) over a  $2\theta$  range from  $10^\circ$  to  $70^\circ$  at a scan rate of  $10^\circ\ \text{min}^{-1}$ . The morphology and microstructure were observed using a scanning electron microscope (FESEM, GeminiSEM 360, ZEISS, Germany). The bonding configurations and charge transfer process of the products were determined with X-ray photoelectron spectroscopy measurements (XPS, AXIS SUPRA+, SHIMADZU, Japan), the binding energies of the tested elements were adjusted based on the indefinite carbon peak at 284.8 eV. The optical transmittance of the samples was measured using a UV-vis spectrophotometer (N4S, INESA, China). The electrochemical measurements were

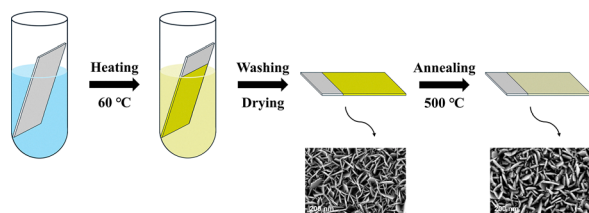


Fig. 1 Scheme of preparation route for the  $\text{WO}_3$  films.

carried out on an electrochemical workstation (CS2350M, Wuhan Corrtest Instrument, China) using a three-electrode system consisting of a standard Ag/AgCl electrode as the reference electrode (RE), a platinum plate as the counter electrode (CE) and the fabricated  $\text{WO}_3/\text{FTO}$  as the working electrode (WE) in 0.5 M  $\text{H}_2\text{SO}_4$ . The *in situ* electrochromic test was carried out by combining the spectrophotometer and electrochemical workstation above. It was carried out in a 0.1 M  $\text{LiClO}_4/\text{PC}$  with a two-electrode system consisting of a platinum plate as the counter electrode and the as-prepared  $\text{WO}_3/\text{FTO}$  as the working electrode.

# 3 Results and discussion

## 3.1 Composition and structure

Fig. 2 displays the XRD patterns of the as-prepared  $\text{H}_2\text{WO}_4$  and  $\text{WO}_3$  samples. As depicted in Fig. 2a, all H series samples matched the  $\text{H}_2\text{WO}_4$  phase (JCPDS No. 43-0679). A peak at  $16.4^\circ$ , corresponding to the (020) plane, showed an increasing trend from  $\text{H}_1$  to  $\text{H}_9$ . Meanwhile, the peak at  $25.6^\circ$ , associated with the (111) plane, increased from  $\text{H}_1$  to  $\text{H}_5$  and then decreased. Another notable peak at  $34.0^\circ$ , corresponding to the (200) plane, increased from  $\text{H}_1$  to  $\text{H}_6$  before decreasing. The varying peak intensities indicated that controlling the addition of  $\text{H}_2\text{C}_2\text{O}_4$  altered the preferential growth direction of the  $\text{H}_2\text{WO}_4$  nanosheets. Our previous research confirmed that the exposed facet of  $\text{H}_2\text{WO}_4$  nanosheets prepared by this method was the (020) plane. The peaks at  $26.4^\circ$  were attributed to FTO; a higher intensity suggested a thinner  $\text{H}_2\text{WO}_4$  film. Notably,  $\text{H}_1$  and  $\text{H}_9$  in Fig. 2a were particularly thin.

In Fig. 2b, all W series samples matched the  $\text{WO}_3$  phase (JCPDS No. 43-1035). The three peaks located between  $20^\circ$  to  $25^\circ$  are characteristic peaks of  $\text{WO}_3$ , indexed to the (002), (020), and (200) planes, respectively. The peak intensity of the (002) plane increased with the addition of  $\text{H}_2\text{C}_2\text{O}_4$ , reaching its maximum in sample  $\text{W}_5$ . Another peak, located at  $34.1^\circ$  and indexed to the (202) plane, showed a significant change, peaking in sample  $\text{W}_7$ . These peak intensities revealed a specific orientation in the as-obtained samples, indicative of a nanosheet morphology rather than bulk, as confirmed by SEM images. Additionally, comparing the peak intensities of  $\text{H}_2\text{WO}_4$  with those of  $\text{WO}_3$  samples, a potential correlation can be inferred. Both the (020) plane of  $\text{H}_2\text{WO}_4$  and the (002) plane of  $\text{WO}_3$  exhibited a growth trend with increasing  $\text{H}_2\text{C}_2\text{O}_4$  addition, suggesting that the (002) plane of  $\text{WO}_3$  may have transformed from the (020) plane of  $\text{H}_2\text{WO}_4$ . Similarly, the (200) and

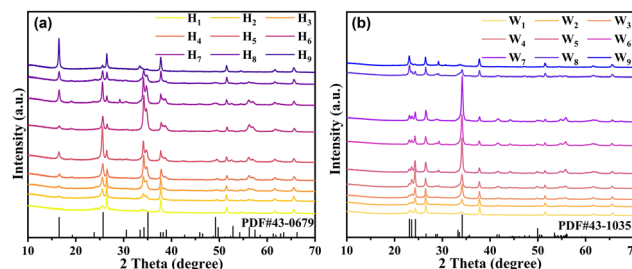


Fig. 2 XRD patterns of (a)  $\text{H}_1\text{--H}_9$  samples and (b)  $\text{W}_1\text{--W}_9$  samples.



(202) planes of  $\text{WO}_3$  are likely derived from the (111) and (200) planes of  $\text{H}_2\text{WO}_4$ , respectively.

The top-view SEM images of the as-prepared  $\text{H}_2\text{WO}_4$  and  $\text{WO}_3$  samples are presented in Fig. 3 and 4. Fig. 3 reveals that all samples were composed of numerous nanosheets oriented vertically to the substrate. As the concentration of  $\text{H}_2\text{C}_2\text{O}_4$  increased from sample  $\text{H}_1$  to  $\text{H}_9$ , three major changes were observed. Firstly, the surface of the  $\text{H}_2\text{WO}_4$  film in  $\text{H}_1$  was smooth, becoming progressively rougher from  $\text{H}_1$  to  $\text{H}_6$ . For samples  $\text{H}_7$ ,  $\text{H}_8$ , and  $\text{H}_9$ , the thin film transitioned into distributed micro-nano islands. Secondly, by measuring 20 random nanosheets (Fig. S2), the average thicknesses of single nanosheets in samples  $\text{H}_1$  through  $\text{H}_9$  were 25.92, 31.12, 37.65, 49.37, 64.83, 84.62, 78.33, 77.65, and 82.92 nm, respectively. This trend indicates that the thickness of the nanosheets increased with the addition of  $\text{H}_2\text{C}_2\text{O}_4$ , reaching a stable value around 80 nm. Lastly, the as-prepared  $\text{H}_2\text{WO}_4$  samples exhibited a square exposed surface, with side lengths increasing from  $\text{H}_1$  to  $\text{H}_9$ . The side length increased from 270 nm for  $\text{H}_1$  to 1800 nm for  $\text{H}_9$ . In Fig. S2, the surface of the  $\text{H}_2\text{WO}_4$  nanosheets is clearly visible, demonstrating that the thickness of the nanosheet in the H series samples increased with the increasing amount of  $\text{H}_2\text{C}_2\text{O}_4$ . Additionally, the thicker

nanosheets in  $\text{H}_7$ ,  $\text{H}_8$ , and  $\text{H}_9$  prefer to grow from the surfaces of other nanosheets rather than the FTO substrate.

In our previous work, we successfully achieved the growth of  $\text{H}_2\text{WO}_4$  nanosheets on various substrates and their self-assembly in solution. The results indicate that  $\text{Na}_2\text{WO}_4$  hydrolyzes under acidic conditions to form insoluble  $\text{H}_2\text{WO}_4$  precursors, which preferentially grow at hydrophilic interfaces rich in  $-\text{OH}$ . Oxalic acid, as a complexing agent, can regulate the hydrolysis rate and nucleation rate of  $\text{WO}_4^{2-}$  by adjusting its concentration. In short, the higher the concentration of oxalic acid, the more  $\text{WO}_4^{2-}$  participate in the oxalic acid coordination, resulting in slower hydrolysis and nucleation rates, and thinner nanosheets and thin films being formed.

Fig. 4 illustrates that the morphologies of the  $\text{WO}_3$  samples closely resemble those of the  $\text{H}_2\text{WO}_4$  ones, indicating the high stability of the as-fabricated films under calcination. By measuring 20 random nanosheets from Fig. S4, the thicknesses of samples  $\text{W}_1$  through  $\text{W}_9$  were determined to be 43.09, 39.48, 48.84, 50.45, 70.79, 82.63, 84.53, 81.25, and 83.34 nm, respectively. The thicknesses of  $\text{W}_4$  through  $\text{W}_9$  were notably similar to those of  $\text{H}_4$  through  $\text{H}_9$ . However, for  $\text{W}_1$ ,  $\text{W}_2$ , and  $\text{W}_3$ , the thicknesses showed a marked increase compared to  $\text{H}_1$ ,  $\text{H}_2$ , and  $\text{H}_3$ . From Fig. S4, although the morphologies of the W series samples were analogous to those of the H series, the corners of the  $\text{WO}_3$  nanosheets were less sharp than those of the  $\text{H}_2\text{WO}_4$  nanosheets. Additionally, the surfaces of the  $\text{WO}_3$  nanosheets were not as smooth as those of the  $\text{H}_2\text{WO}_4$  nanosheets. As observed in Fig. S4e, some concavities are present on the surface of the nanosheets, which can be categorized into two types. Point-like pores were caused by stress during the transformation of the crystal structure, resulting in surface breakage on the nanosheet surface. Rod-like pores were attributed to the detachment of nanosheets growing on the primary nanosheet substrate during the annealing process.

The thicknesses of the as-prepared  $\text{WO}_3$  films were determined using side-view SEM. Fig. 5 indicates that the FTO layer exhibited a consistent thickness across samples, confirming a uniform test environment. As shown in Fig. 5, sample  $\text{W}_1$  exhibited the thinnest thickness, approximately 370 nm. The

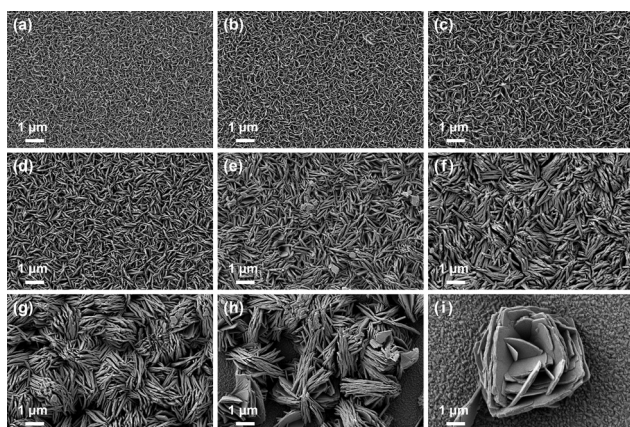


Fig. 3 (a)–(i) SEM images of  $\text{H}_2\text{WO}_4/\text{FTO}$  samples ( $\text{H}_1$ – $\text{H}_9$ ).

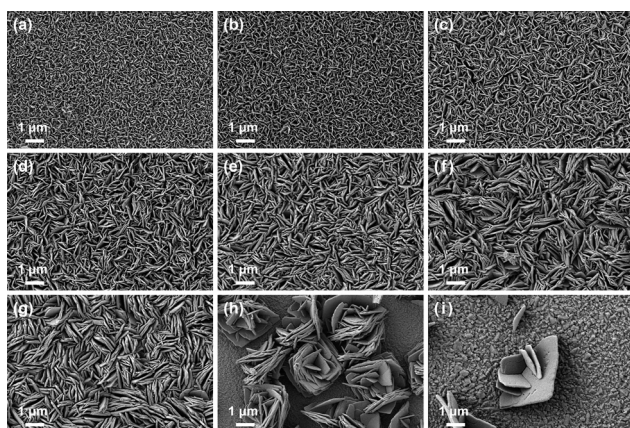


Fig. 4 (a)–(i) SEM images of  $\text{WO}_3/\text{FTO}$  samples ( $\text{W}_1$ – $\text{W}_9$ ).

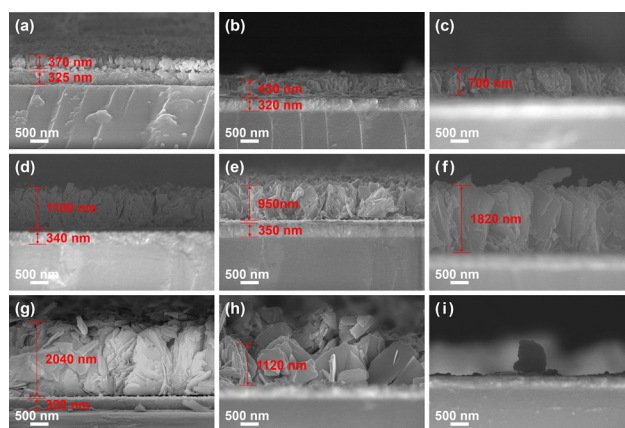


Fig. 5 (a)–(i) Cross section SEM images of  $\text{WO}_3/\text{FTO}$  samples ( $\text{W}_1$ – $\text{W}_9$ ).



thickness increased from  $W_1$  to  $W_7$ , with the exception of  $W_5$ . The  $W_8$  film demonstrated a thickness of 1120 nm. For  $W_9$ , given its composition of dispersed micro-nano islands, the film structure could not be discerned in its SEM images. The SEM images further revealed that from  $W_1$  to  $W_6$ , the thickness of the  $WO_3$  film was analogous to the length of its constituent nanosheets, suggesting that the film was directly composed of  $WO_3$  nanosheets growing on the FTO substrate. In the case of  $W_7$  and  $W_8$ , the film comprised  $WO_3$  nanosheets growing on the FTO substrate and secondary  $WO_3$  nanosheets growing on the primary ones, which contributed to the overall increased thickness of the  $WO_3$  film.

XPS analysis was conducted to investigate the surface chemical composition and the chemical state of each element in the fabricated  $WO_3$  films. Since samples  $W_1$  through  $W_6$  displayed minimal differences in their full-spectrum and high-resolution spectra, only samples  $W_1$ ,  $W_7$ ,  $W_8$ , and  $W_9$  were selected for further comparison in this section. Fig. 6a reveals characteristic signals for W and O in the full spectra of both samples, confirming the presence of  $WO_3$ . However, in  $W_9$ , Sn peaks were also detected, attributed to the structure of its dispersed micro-nano islands. As depicted in Fig. 6b,  $W_1$  and  $W_7$  exhibited similar W 4f and W 5p peaks, with a flat region at 27 eV, corresponding to the binding energy of Sn 4d. In  $W_8$ , the intensity of the W 4f and W 5p peaks diminished, and a peak emerged at 27 eV. In  $W_9$ , the peak at 27 eV was more pronounced, and the W 4f peaks shifted to lower binding energies. This phenomenon indicates a strong interaction between the FTO layer and  $WO_3$ , leading to the formation of a heterojunction.

UV-Vis transmittance spectra were employed to assess the optical characteristics of the as-prepared samples. Considering their potential application in smart windows, the samples should exhibit high transmittance in their bleached state. Fig. 7a shows that the FTO-based glass demonstrated high

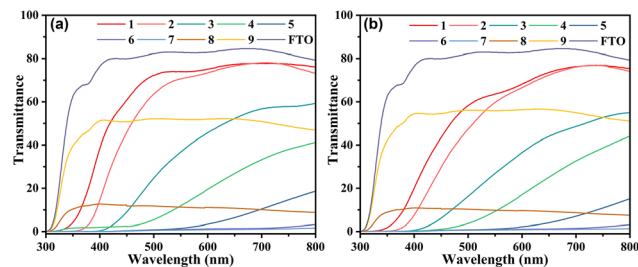


Fig. 7 UV-Vis transmittance spectra of as-prepared (a)  $H_2WO_4$ /FTO and (b)  $WO_3$ /FTO samples.

transmittance in the visible light region, approximately 80% from 400 to 800 nm. Among all H series samples,  $H_1$  exhibited the highest transmittance, with 77% of incident light passing through from 500 to 800 nm.  $H_2$  displayed a similarly high light transmittance to  $H_1$ , with a slight red shift. Subsequently, the light transmittance of the samples decreased with an increase in sample number until  $H_7$ . For  $H_8$  and  $H_9$ , as the films were not continuous but rather had a distributed micro-nano islands structure, these samples showed a similar transmittance trend in 300 to 800 nm to FTO with a marked decrease in transmittance.

For the  $WO_3$  samples, as shown in Fig. 7b, the UV-vis transmittance spectra revealed a high degree of similarity to those in Fig. 7a.  $W_1$  had the highest transmittance among all W series samples, followed by  $W_2$ . The curves for  $W_3$  to  $W_9$  closely matched those of  $H_3$  to  $H_9$ , particularly  $H_8$  and  $H_9$ . This indicates that in  $W_3$  to  $W_9$ , the transmittance of the entire sample was primarily determined by the large thickness of the  $WO_3$  film. In contrast, in  $W_1$  and  $W_2$ , the bandgap played the main role in determining transmittance.

### 3.2 Electrochemical and electrochromic properties

To obtain the electrochemical characteristics of the as-prepared samples, cyclic voltammetry (CV) curves were examined at various scan rates (5, 10, 20, 50, 100  $mV s^{-1}$ ) within the potential window of  $-0.3$  V to 0.6 V (vs. Ag/AgCl). Upon application of an initial voltage of  $-0.3$  V, the samples transformed into a dark blue color. As the voltage increased, the electrode materials progressively lightened. With rising scan rates, the anodic peak shifted to a more positive potential. Concurrently, the area of the curve, indicative of capacitance, broadened. This capacitive behavior can be attributed to several mechanisms, such as the adsorption of a monolayer of ions onto the electrode surface, surface redox reactions, or ion intercalation without a phase transition. In this context, the redox reaction pertains to the insertion and extraction of  $H^+$  ions and electrons within the  $WO_3$  matrix, resulting in a reversible change in transmittance between blue and yellow states as follows:

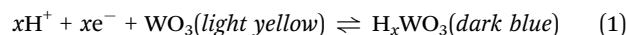


Fig. 8a–i demonstrate that samples  $W_1$  and  $W_2$  exhibit significantly enhanced current and larger voltammogram areas compared to  $W_3$ ,  $W_4$ , and  $W_5$ . This indicates a pronounced electrochemical

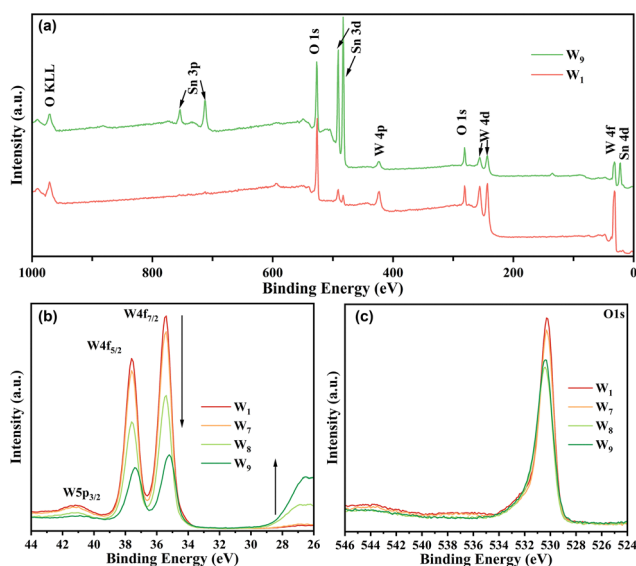


Fig. 6 (a) Survey scan XPS spectra of  $W_1$  and  $W_9$ , and the high-resolution XPS spectra for (b) W 4f and (c) O 1s of  $W_1$ ,  $W_7$ ,  $W_8$  and  $W_9$ .



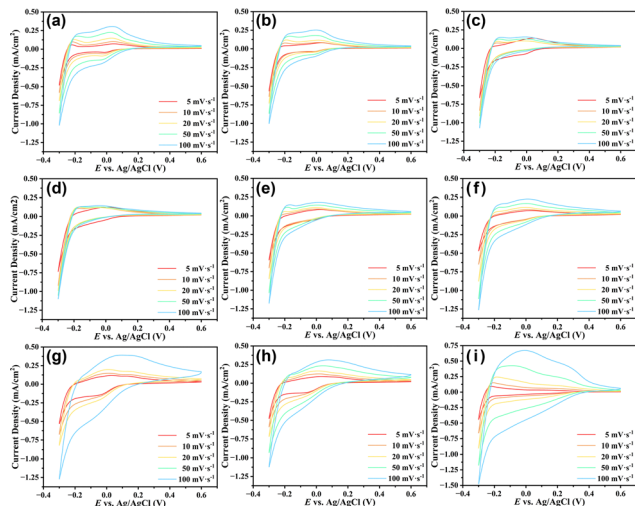


Fig. 8 (a)–(i) The cyclic voltammetry of  $W_1$ – $W_9$  under different scan rates.

activity and ion storage capacity during the electrochromic process. These observations are attributed to the rapid charge transfer kinetics and low internal resistance, which stem from the thin nanosheet and film thicknesses. However, although samples  $W_6$ ,  $W_7$ ,  $W_8$ , and  $W_9$  also show large voltammogram areas, these samples experienced damage during the test which was also shown in Fig. 10 after *in situ* UV-vis transmittance testing. The increased voltammogram areas are ascribed to the electrochemical performance of the FTO matrix.

To directly examine the electrochromic properties of  $WO_3$  films, *in situ* UV-vis spectrometry was employed. The setup for the *in situ* system is shown in Fig. 9. For these tests, a 0.1 M  $LiClO_4$ /propylene carbonate (PC) solution in a quartz reactor served as a blank. The samples were subjected to a voltage bias sequence of +1.0 V, followed by 0, –0.2, –0.4, –0.6, –0.8, and –1.0 V (*vs.* Ag/AgCl).

Fig. 10 illustrates the electrochromic performance of the W series samples. As a cathodic electrochromic material, the  $WO_3$  film can alternate its color between light yellow and dark blue under a square wave potential ranging from +1.0 V to –1.0 V in a  $LiClO_4$ /PC solution. Under a negative bias,  $Li^+$  ions are inserted into the crystal lattice of  $WO_3$ , causing the film to turn dark blue. Conversely, when a positive bias is applied,  $Li^+$  ions

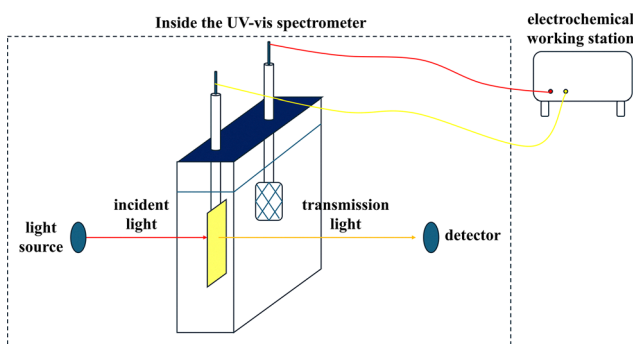


Fig. 9 Scheme of *in situ* transmittance testing system.

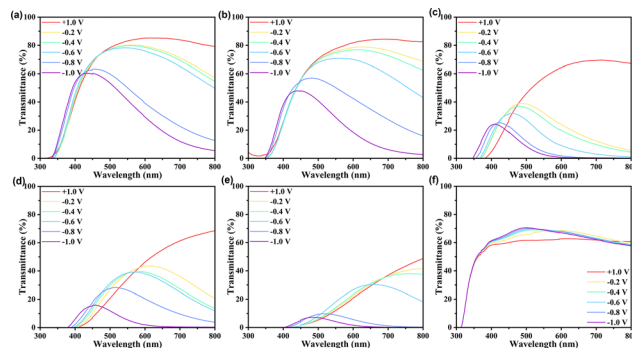
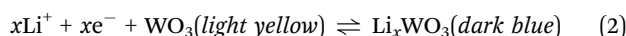


Fig. 10 *In situ* UV-vis spectra of (a)  $W_1$ , (b)  $W_2$ , (c)  $W_3$ , (d)  $W_4$ , (e)  $W_5$  and (f)  $W_9$ .

are extracted from the lattice, leading to the film's lightening. The electrochromic reaction can be described as follows:



As shown in Fig. 10, the transmittances at 620 nm in the bleached state ( $T_b$ ) at a potential of –1.0 V were 86.06%, 82.87%, 66.29%, 50.11%, 24.27%, and 68.40% for samples  $W_1$ ,  $W_2$ ,  $W_3$ ,  $W_4$ ,  $W_5$ , and  $W_9$ , respectively. Conversely, the transmittances at 620 nm in the colored state ( $T_c$ ) at a potential of +1.0 V were 25.09%, 15.02%, 0.55%, 1.32%, 1.04%, and 66.15% for  $W_1$ ,  $W_2$ ,  $W_3$ ,  $W_4$ ,  $W_5$ , and  $W_9$ , respectively. For samples  $W_6$ ,  $W_7$ , and  $W_8$ , the electrochromic layers were compromised during the coloring process, likely due to lattice expansion associated with the insertion of  $Li^+$  ions. In contrast, the other samples, characterized by thinner single nanosheets and overall electrochromic films, exhibited greater flexibility, which contributed to their resilience against lattice expansion.

The optical images of the as-prepared samples are displayed in Fig. 11. The H series samples exhibited a grayish-green hue, whereas the W series samples turned light yellow after annealing. Following the coloring process, all samples transformed into a blue color. It is evident from the images that samples  $H_4$  to  $H_8$  and  $W_4$  to  $W_8$  exhibited significant haze, as the logos and text beneath the samples were indistinct, rendering them unsuitable for smart window applications. Samples  $W_1$  and  $W_9$ , while appearing uniform in the bleached state, demonstrated

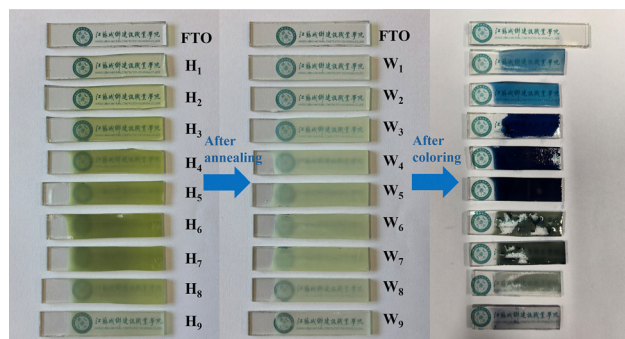


Fig. 11 Optical images of as-prepared  $H_2WO_4$ /FTO,  $WO_3$ /FTO samples and  $WO_3$ /FTO samples after coloring.



uneven color distribution in the colored state, revealing their heterogeneous distribution of film thickness.

## 4 Conclusions

In conclusion, the mild chemical bath deposition method was employed to fabricate WO<sub>3</sub> films on FTO substrates. By controlling the amounts of reactants, the optical properties of the WO<sub>3</sub> films could be effectively modulated. The findings indicate that films with thinner compositions, both in terms of overall thickness and individual nanosheets, result in electrochromic films that are more transparent and flexible. The optimal samples exhibited a high degree of optical modulation, with a transmittance change ( $\Delta T$ ) of 67.85% at 620 nm and demonstrated good cycling stability. Furthermore, the thickness of the electrochromic films could be tuned from 370 nm to 2040 nm, show a viable approach for the large-scale production of WO<sub>3</sub>-based smart windows suitable for commercial, tunable electrochromic applications.

## Author contributions

J. Y.: conceptualization, methodology, investigation, validation, writing – original draft, supervision, funding acquisition; G. L.: methodology, investigation, resources, funding acquisition; M. Z.: methodology, investigation, resources, supervision.

## Conflicts of interest

There are no conflicts to declare.

## Data availability

The data supporting this article have been included as part of the supplementary information (SI). Supplementary information is available. See DOI: <https://doi.org/10.1039/d5ma01024a>.

Raw data files are available from the corresponding author.

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